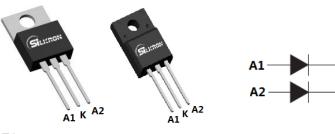


#### **Main Product Characteristics:**

IF	2×5A
VRRM	100V
T <sub>j</sub> (max)	<b>150</b> ℃
Vf(max)	0.8V



TO220 SSBD10100CT TO220F SSBD10100CTF

Schematic Diagram

#### **Features and Benefits:**

- High Junction Temperature
- High ESD Protection
- High Forward & Reverse Surge capability



#### **Description:**

Schottky Barrier Rectifier designed for high frequency switch model power supplies such as adaptors and DC/DC convertors; this product special design for high forward and reverse surge capability

## **Absolute Rating:**

Symbol	Characterizes	Value	Unit	
$V_{RRM}$	Peak Repetitive Reverse Voltage	100	V	
V <sub>R(RMS)</sub>	RMS Reverse Voltage	70	V	
	A	Per diode	5	Α
I <sub>F(AV)</sub>	Average Forward Current	Per device	10	Α
I <sub>FSM</sub>	Non Repetitive Surge Forward Curre	180	Α	
I <sub>RRM</sub>	Peak Repetitive Reverse Surge Curr	0.5	Α	
TJ	Maximum operation Junction Temper	-55~150	$^{\circ}$	
T <sub>stg</sub>	Storage Temperature Range	-55~150	$^{\circ}$	

#### **Thermal Resistance**

Symbol	Characterizes	Value	Unit	
$R_{ heta JC}$	Maximum Thermal Resistance Junction To	2	°C/W	
$R_{ heta JC}$	Case(per leg)	TO220F	4	°C/W

#### Electrical Characterizes @T<sub>A</sub>=25℃ unless otherwise specified

Symbol	Characterizes	Min	Тур	Max	Unit	Test Condition
$V_R$	Reverse Breakdown Voltage	100			>	I <sub>R</sub> =0.5mA
V <sub>F</sub> Forward Voltage Drop				0.8	\/	I <sub>F</sub> =5A, T <sub>J</sub> =25℃
				0.7	V	I <sub>F</sub> =5A, T <sub>J</sub> =125℃
I <sub>R</sub>	Leakage Current			0.1	mΛ	V <sub>R</sub> =100V, T <sub>J</sub> =25℃
				10	mA	V <sub>R</sub> =100V, T <sub>J</sub> =125℃

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## I-V Curves:

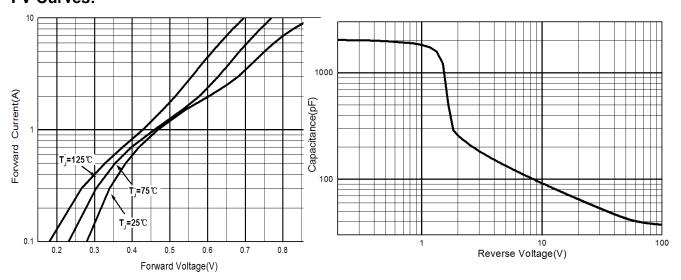


Figure 1: Typical Forward Characteristics Figure 2: Typical Capacitance Characteristics

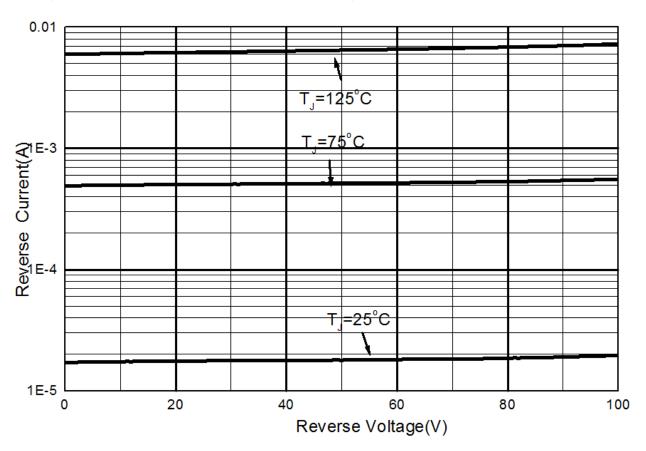


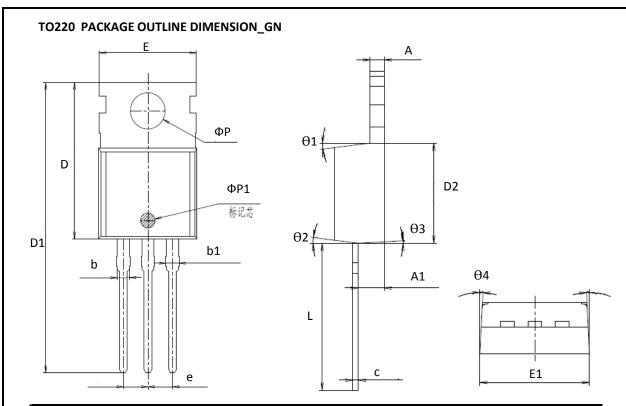
Figure 3: Typical Reverse Characteristics





## **Mechanical Data:**

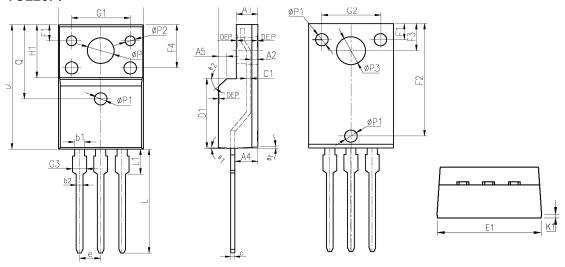
#### TO220:



Symbol	Dimension In Millimeters			Dimension In Inches		
Symbol	Min	Nom	Max	Min	Nom	Max
Α	-	1.300	-	-	0.051	-
A1	2.200	2.400	2.600	0.087	0.094	0.102
b	-	1.270	1	-	0.050	-
b1	1.270	1.370	1.470	0.050	0.054	0.058
С	-	0.500	ı	ı	0.020	-
D	-	15.600	1	-	0.614	-
D1	-	28.700	1	-	1.130	-
D2	-	9.150	-	-	0.360	-
Е	9.900	10.000	10.100	0.390	0.394	0.398
E1	-	10.160	1	-	0.400	-
ΦР	-	3.600	1	ı	0.142	-
ФР1		1.500		0.059		
е		2.54BSC			0.1BSC	
L	12.900	13.100	13.300	0.508	0.516	0.524
θ1	-	<b>7</b> <sup>0</sup>	-	-	<b>7</b> <sup>0</sup>	-
Θ2	-	7 <sup>0</sup>	-	-	7 <sup>0</sup>	-
Θ3	-	3 <sup>0</sup>	-	5 <sup>0</sup>	7 <sup>0</sup>	90
Θ4	-	3 <sup>0</sup>	-	1 <sup>0</sup>	3 <sup>0</sup>	5 <sup>0</sup>



## TO220F:



Symbol	Dimension In Millimeters		Di	hes			
Symbol	Min	Nom	Max	Min	Nom	Max	
E	10.040	10.200	10.360	0.395	0.402	0.408	
Α	4.500	4.700	4.900	0.177	0.185	0.193	
A1	2.340	2.540	2.740	0.092	0.100	0.108	
A2	0.950	1.050	1.150	0.037	0.041	0.045	
A4	2.650	2.750	2.850	0.104	0.108	0.112	
A5		1.00REF			0.039REF		
С	0.420	0.500	0.580	0.017	0.020	0.023	
c1	0.420	0.500	0.580	0.017	0.020	0.023	
D	15.670	15.870	16.070	0.617	0.625	0.633	
Q		9.20REF			0.362REF		
H1		6.70REF			0.264REF		
е		2.54BSC			0.10BSC	C	
ΦР		3.183REF			0.125REF		
L	12.780	12.980	13.180	0.503	0.511	0.519	
L1	3.250	3.450	3.650	0.128	0.136	0.144	
D1		9.17REF		0.362REF			
ФР1	1.400	1.500	1.600	0.055	0.059	0.063	
ФР2	1.150	1.200	1.250	0.045	0.047	0.049	
ФР3		3.45REF		0.136REF			
<b>Θ</b> 1	5°	7°	9°	5°	7°	9°	
Θ2	-	45°	-	-	45°	-	
DEP	0.050	0.100	0.150	0.002	0.004	0.006	
F1	1.900	2.000	2.100	0.075	0.079	0.083	
F2	13.800	13.900	14.000	0.543	0.547	0.551	
F3	3.200	3.300	3.400	0.126	0.130	0.134	
F4	5.300	5.400	5.500	0.209	0.213	0.217	
G1	6.600	6.700	6.800	0.260	0.264	0.268	
G2	6.900	7.000	7.100	0.272	0.276	0.280	
G3	1.100	1.300	1.500	0.043	0.051	0.059	
E1	9.900	10.000	10.100	0.390	0.394	0.398	
K1	0.650	0.700	0.750	0.026	0.028	0.030	
b1	1.050	1.200	1.350	0.041	0.047	0.053	
b2	0.700	0.800	0.850	0.028	0.031	0.033	



# **Ordering and Marking Information**

Device Marking: SSBD100100CT&SSBD10100CTF

Package (Available)
TO-220&TO220F
Operating Temperature Range
C:-55 to 150 °C

**Devices per Unit** 

Package Type	Units/ Tube	Tubes/Inner Box	Units/In ner Box	Inner Boxes/Carton Box	Units/Carto n Box
TO220	50	20	1000	6	6000
TO220F	50	20	1000	6	6000

**Reliability Test Program** 

Test Item	Conditions	Duration	Sample Size
High	Tj=125℃ to 150℃ @	168 hours	3 lots x 77 devices
Temperature	80% of Max	500 hours	
Reverse	VDSS/VCES/VR	1000 hours	
Bias(HTRB)			

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